

FEATURES

Supply range

2.8 V to 15 V, ADR291

4.4 V to 15 V, ADR292

Supply current: 15 μ A maximum

Low noise: 8 μ V and 12 μ V p-p (0.1 Hz to 10 Hz)

High output current: 5 mA

Temperature range: -40°C to $+125^{\circ}\text{C}$

Pin-compatible with REF02/REF19x

APPLICATIONS

Portable instrumentation

Precision reference for 3 V and 5 V systems

Analog-to-digital and digital-to-analog converter reference

Solar-powered applications

Loop-current-powered instruments

GENERAL DESCRIPTION

The ADR291 and ADR292 are low noise, micropower precision voltage references that use an XFET[®] reference circuit. The new XFET architecture offers significant performance improvements over traditional band gap and buried Zener-based references. Improvements include one quarter the voltage noise output of band gap references operating at the same current, very low and ultralinear temperature drift, low thermal hysteresis, and excellent long-term stability.

The ADR291/ADR292 family is a series of voltage references providing stable and accurate output voltages from supplies as low as 2.8 V for the ADR291. Output voltage options are 2.5 V and 4.096 V for the ADR291 and ADR292, respectively.

Quiescent current is only 12 μ A, making these devices ideal for battery-powered instrumentation. Three electrical grades are available offering initial output accuracies of ± 2 mV, ± 3 mV, and ± 6 mV maximum for the ADR291, and ± 3 mV, ± 4 mV, and ± 6 mV maximum for the ADR292. Temperature

coefficients for the three grades are 8 ppm/ $^{\circ}\text{C}$, 15 ppm/ $^{\circ}\text{C}$, and 25 ppm/ $^{\circ}\text{C}$ maximum, respectively. Line regulation and load regulation are typically 30 ppm/V and 30 ppm/mA, maintaining the reference's overall high performance. For a device with 5.0 V output, refer to the ADR293 data sheet.

The ADR291 and ADR292 references are specified over the extended industrial temperature range of -40°C to $+125^{\circ}\text{C}$. Devices are available in the 8-lead SOIC, 8-lead TSSOP, and 3-lead TO-92 packages.

Table 1. ADR291/ADR292 Product

| Part No. | Output Voltage (V) | Initial Accuracy ($\pm\%$) | Temperature Coefficient (ppm/ $^{\circ}\text{C}$) Max |
|----------|--------------------|------------------------------|--|
| ADR291 | 2.500 | 0.08, 0.12, 0.24 | 8, 15, 25 |
| ADR292 | 4.096 | 0.07, 0.10, 0.15 | 8, 15, 25 |

CONNECTION DIAGRAMS

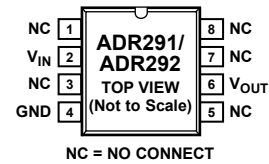


Figure 1. 8-Lead SOIC (R-8)

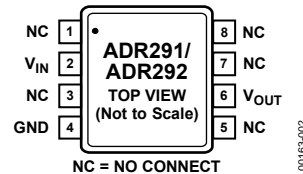


Figure 2. 8-Lead TSSOP (RU-8)

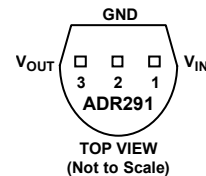


Figure 3. 3-Lead TO-92 (T-3)

Rev. F

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REVISION HISTORY

5/11—Rev. E to Rev. F

| | |
|--|----|
| Deleted Negative Precision Reference Without Precision Resistors Section | 14 |
| Deleted Figure 33 and Figure 34, Renumbered Sequentially ... | 14 |
| Changes to Ordering Guide | 17 |

12/07—Rev. D to Rev. E

| | |
|---------------------------|----|
| Changes to Features..... | 1 |
| Changes to Figure 34..... | 14 |

3/06—Rev. C to Rev. D

| | |
|----------------------------------|-----------|
| Updated Format..... | Universal |
| Change to Table 8 | 6 |
| Updated Outline Dimensions | 15 |
| Changes to Ordering Guide | 16 |

9/03—Rev. B to Rev. C

| | |
|----------------------------------|-----------|
| Deleted ADR290..... | Universal |
| Changes to Specifications..... | 2 |
| Changes to Ordering Guide | 4 |
| Updated Outline Dimensions | 13 |

SPECIFICATIONS

ADR291 ELECTRICAL SPECIFICATIONS

$V_S = 3.0\text{ V to }15\text{ V}$, $T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 2.

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|------------------------|----------------------------------|---|-------|-------|-------|------------------------------|
| E GRADE | | | | | | |
| Output Voltage | V_{OUT} | $I_{OUT} = 0\text{ mA}$ | 2.498 | 2.500 | 2.502 | V |
| Initial Accuracy | V_{OERR} | | -2 | | +2 | mV |
| | | | -0.08 | | +0.08 | % |
| F GRADE | | | | | | |
| Output Voltage | V_{OUT} | $I_{OUT} = 0\text{ mA}$ | 2.497 | 2.500 | 2.503 | V |
| Initial Accuracy | V_{OERR} | | -3 | | +3 | mV |
| | | | -0.12 | | +0.12 | % |
| G GRADE | | | | | | |
| Output Voltage | V_{OUT} | $I_{OUT} = 0\text{ mA}$ | 2.494 | 2.500 | 2.506 | V |
| Initial Accuracy | V_{OERR} | | -6 | | +6 | mV |
| | | | -0.24 | | +0.24 | % |
| LINE REGULATION | | | | | | |
| E/F Grades | $\Delta V_{OUT}/\Delta V_{IN}$ | $I_{OUT} = 0\text{ mA}$ | | 30 | 100 | ppm/V |
| G Grade | | | | 40 | 125 | ppm/V |
| LOAD REGULATION | | | | | | |
| E/F Grades | $\Delta V_{OUT}/\Delta I_{LOAD}$ | $V_S = 5.0\text{ V}$, $I_{OUT} = 0\text{ mA to }5\text{ mA}$ | | 30 | 100 | ppm/mA |
| G Grade | | | | 40 | 125 | ppm/mA |
| LONG-TERM STABILITY | ΔV_{OUT} | After 1000 hours of operation @ 125°C | | 50 | | ppm |
| NOISE VOLTAGE | e_N | 0.1 Hz to 10 Hz | | 8 | | $\mu\text{V p-p}$ |
| WIDEBAND NOISE DENSITY | e_N | @ 1 kHz | | 480 | | $\text{nV}/\sqrt{\text{Hz}}$ |

$V_S = 3.0\text{ V to }15\text{ V}$, $T_A = -25^\circ\text{C to }+85^\circ\text{C}$, unless otherwise noted.

Table 3.

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|-------------------------|----------------------------------|---|-----|-----|-----|-----------------------|
| TEMPERATURE COEFFICIENT | | | | | | |
| E Grade | TCV_{OUT} | $I_{OUT} = 0\text{ mA}$ | | 3 | 8 | ppm/ $^\circ\text{C}$ |
| F Grade | | | | 5 | 15 | ppm/ $^\circ\text{C}$ |
| G Grade | | | | 10 | 25 | ppm/ $^\circ\text{C}$ |
| LINE REGULATION | | | | | | |
| E/F Grades | $\Delta V_{OUT}/\Delta V_{IN}$ | $I_{OUT} = 0\text{ mA}$ | | 35 | 125 | ppm/V |
| G Grade | | | | 50 | 150 | ppm/V |
| LOAD REGULATION | | | | | | |
| E/F Grades | $\Delta V_{OUT}/\Delta I_{LOAD}$ | $V_S = 5.0\text{ V}$, $I_{OUT} = 0\text{ mA to }5\text{ mA}$ | | 20 | 125 | ppm/mA |
| G Grade | | | | 30 | 150 | ppm/mA |

ADR291/ADR292

$V_S = 3.0\text{ V to }15\text{ V}$, $T_A = -40^\circ\text{C to }+125^\circ\text{C}$, unless otherwise noted.

Table 4.

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|-------------------------|----------------------------------|--|-----|-----|-----|-----------------------|
| TEMPERATURE COEFFICIENT | | | | | | |
| E Grade | TCV_{OUT} | $I_{OUT} = 0\text{ mA}$ | | 3 | 10 | ppm/ $^\circ\text{C}$ |
| F Grade | | | | 5 | 20 | ppm/ $^\circ\text{C}$ |
| G Grade | | | | 10 | 30 | ppm/ $^\circ\text{C}$ |
| LINE REGULATION | | | | | | |
| E/F Grades | $\Delta V_{OUT}/\Delta V_{IN}$ | $I_{OUT} = 0\text{ mA}$ | | 40 | 200 | ppm/V |
| G Grade | | | | 70 | 250 | ppm/V |
| LOAD REGULATION | | | | | | |
| E/F Grades | $\Delta V_{OUT}/\Delta I_{LOAD}$ | $V_S = 5.0\text{ V}$, $I_{OUT} = 0\text{ mA to }5\text{ mA}$ | | 20 | 200 | ppm/mA |
| G Grade | | | | 30 | 300 | ppm/mA |
| SUPPLY CURRENT | I_S | $T_A = 25^\circ\text{C}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ | | 9 | 12 | μA |
| | | | | 12 | 15 | μA |
| THERMAL HYSTERESIS | $V_{OUT-HYS}$ | 8-lead SOIC, 8-lead TSSOP | | 50 | | ppm |

ADR292 ELECTRICAL SPECIFICATIONS

$V_S = 5\text{ V to }15\text{ V}$, $T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 5.

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|------------------------|----------------------------------|---|-------|-------|-------|------------------------------|
| E GRADE | | | | | | |
| Output Voltage | V_{OUT} | $I_{OUT} = 0\text{ mA}$ | 4.093 | 4.096 | 4.099 | V |
| Initial Accuracy | V_{OERR} | | -3 | | +3 | mV |
| | | | -0.07 | | +0.07 | % |
| F GRADE | | | | | | |
| Output Voltage | V_{OUT} | $I_{OUT} = 0\text{ mA}$ | 4.092 | 4.096 | 4.1 | V |
| Initial Accuracy | V_{OERR} | | -4 | | +4 | mV |
| | | | -0.10 | | +0.10 | % |
| G GRADE | | | | | | |
| Output Voltage | V_{OUT} | $I_{OUT} = 0\text{ mA}$ | 4.090 | 4.096 | 4.102 | V |
| Initial Accuracy | V_{OERR} | | -6 | | +6 | mV |
| | | | -0.15 | | +0.15 | % |
| LINE REGULATION | | | | | | |
| E/F Grades | $\Delta V_{OUT}/\Delta V_{IN}$ | $V_S = 4.5\text{ V to }15\text{ V}$, $I_{OUT} = 0\text{ mA}$ | | 30 | 100 | ppm/V |
| G Grade | | | | 40 | 125 | ppm/V |
| LOAD REGULATION | | | | | | |
| E/F Grades | $\Delta V_{OUT}/\Delta I_{LOAD}$ | $V_S = 5.0\text{ V}$, $I_{OUT} = 0\text{ mA to }5\text{ mA}$ | | 30 | 100 | ppm/mA |
| G Grade | | | | 40 | 125 | ppm/mA |
| LONG-TERM STABILITY | ΔV_{OUT} | After 1000 hours of operation @ 125°C | | 50 | | ppm |
| NOISE VOLTAGE | e_N | 0.1 Hz to 10 Hz | | 12 | | $\mu\text{V p-p}$ |
| WIDEBAND NOISE DENSITY | e_N | @ 1 kHz | | 640 | | $\text{nV}/\sqrt{\text{Hz}}$ |

$V_S = 5\text{ V to }15\text{ V}$, $T_A = -25^\circ\text{C to }+85^\circ\text{C}$, unless otherwise noted.

Table 6.

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|-------------------------|----------------------------------|---|-----|-----|-----|--------|
| TEMPERATURE COEFFICIENT | | | | | | |
| E Grade | TCV _{OUT} | I _{OUT} = 0 mA | | 3 | 8 | ppm/°C |
| F Grade | | | | 5 | 15 | ppm/°C |
| G Grade | | | | 10 | 25 | ppm/°C |
| LINE REGULATION | | | | | | |
| E/F Grades | $\Delta V_{OUT}/\Delta V_{IN}$ | $V_S = 4.5\text{ V to }15\text{ V}$, I _{OUT} = 0 mA | | 35 | 125 | ppm/V |
| G Grade | | | | 50 | 150 | ppm/V |
| LOAD REGULATION | | | | | | |
| E/F Grades | $\Delta V_{OUT}/\Delta I_{LOAD}$ | $V_S = 5.0\text{ V}$, I _{OUT} = 0 mA to 5 mA | | 20 | 125 | ppm/mA |
| G Grade | | | | 30 | 150 | ppm/mA |

$V_S = 5\text{ V to }15\text{ V}$, $T_A = -40^\circ\text{C to }+125^\circ\text{C}$, unless otherwise noted.

Table 7.

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|-------------------------|----------------------------------|---|-----|----------|----------|----------|
| TEMPERATURE COEFFICIENT | | | | | | |
| E Grade | TCV _{OUT} | I _{OUT} = 0 mA | | 3 | 10 | ppm/°C |
| F Grade | | | | 5 | 20 | ppm/°C |
| G Grade | | | | 10 | 30 | ppm/°C |
| LINE REGULATION | | | | | | |
| E/F Grades | $\Delta V_{OUT}/\Delta V_{IN}$ | $V_S = 4.5\text{ V to }15\text{ V}$, I _{OUT} = 0 mA | | 40 | 200 | ppm/V |
| G Grade | | | | 70 | 250 | ppm/V |
| LOAD REGULATION | | | | | | |
| E/F Grades | $\Delta V_{OUT}/\Delta I_{LOAD}$ | $V_S = 5.0\text{ V}$, I _{OUT} = 0 mA to 5 mA | | 20 | 200 | ppm/mA |
| G Grade | | | | 30 | 300 | ppm/mA |
| SUPPLY CURRENT | I _S | T _A = 25°C -40°C ≤ T _A ≤ +125°C | | 10 12 | 15 18 | μA μA |
| THERMAL HYSTERESIS | V _{OUT-HYS} | 8-lead SOIC, 8-lead TSSOP | | 50 | | ppm |

ABSOLUTE MAXIMUM RATINGS

Remove power before inserting or removing units from their sockets.

Table 8.

| Parameter | Rating |
|---|-----------------|
| Supply Voltage | 18 V |
| Output Short-Circuit Duration to GND | Indefinite |
| Storage Temperature Range T, R, RU Packages | -65°C to +150°C |
| Operating Temperature Range ADR291/ADR292 | -40°C to +125°C |
| Junction Temperature Range T, R, RU Packages | -65°C to +125°C |
| Lead Temperature (Soldering, 60 sec) | 300°C |

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 9. Package Types

| Package Type | θ_{JA}^1 | θ_{JC} | Unit |
|-------------------|-----------------|---------------|------|
| 8-Lead SOIC (R) | 158 | 43 | °C/W |
| 8-Lead TSSOP (RU) | 240 | 43 | °C/W |
| 3-Lead TO-92 (T) | 160 | - | °C/W |

¹ θ_{JA} is specified for worst-case conditions. For example, θ_{JA} is specified for a device in socket testing. In practice, θ_{JA} is specified for a device soldered in the circuit board.

Table 10. Other XFET Products

| Part Number | Nominal Output Voltage (V) | Package Type |
|------------------------|----------------------------|------------------|
| ADR420 | 2.048 | 8-Lead MSOP/SOIC |
| ADR421 | 2.50 | 8-Lead MSOP/SOIC |
| ADR423 | 3.0 | 8-Lead MSOP/SOIC |
| ADR425 | 5.0 | 8-Lead MSOP/SOIC |

ESD CAUTION



ESD (electrostatic discharge) sensitive device.

Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS



Figure 4. 8-Lead SOIC (R-8)



Figure 5. 8-Lead TSSOP (RU-8)



Figure 6. 3-Lead TO-92 (T-3)

Table 11. Pin Function Descriptions

| Pin No. | | | Mnemonic | Description |
|---------------|---------------|-------|------------------|----------------|
| SOIC | TSSOP | TO-92 | | |
| 1, 3, 5, 7, 8 | 1, 3, 5, 7, 8 | N/A | NC | No Connect |
| 2 | 2 | 1 | V _{IN} | Input Voltage |
| 4 | 4 | 2 | GND | Ground |
| 6 | 6 | 3 | V _{OUT} | Output Voltage |

TYPICAL PERFORMANCE CHARACTERISTICS



Figure 7. ADR291 V_{OUT} vs. Temperature



Figure 10. ADR292 Quiescent Current vs. Input Voltage



Figure 8. ADR292 V_{OUT} vs. Temperature



Figure 11. ADR291/ADR292 Supply Current vs. Temperature



Figure 9. ADR291 Quiescent Current vs. Input Voltage



Figure 12. ADR291/ADR292 Line Regulation vs. Temperature



Figure 13. ADR291/ADR292 Line Regulation vs. Temperature



Figure 16. ADR291 Load Regulation vs. Temperature



Figure 14. ADR291 Minimum Input-Output Voltage Differential vs. Load Current



Figure 17. ADR292 Load Regulation vs. Temperature



Figure 15. ADR292 Minimum Input-Output Voltage Differential vs. Load Current



Figure 18. ADR291 ΔV_{OUT} from Nominal vs. Load Current

ADR291/ADR292



Figure 19. ADR292 ΔV_{OUT} from Nominal vs. Load Current

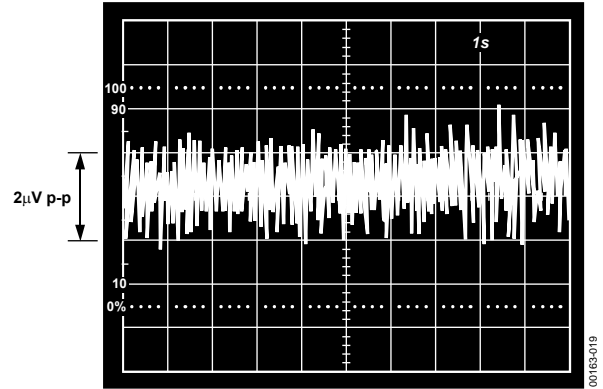


Figure 22. ADR291 0.1 Hz to 10 Hz Noise

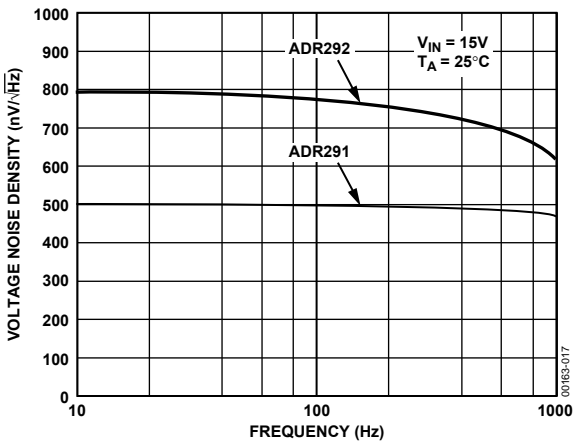


Figure 20. Voltage Noise Density vs. Frequency



Figure 23. ADR291 Output Impedance vs. Frequency

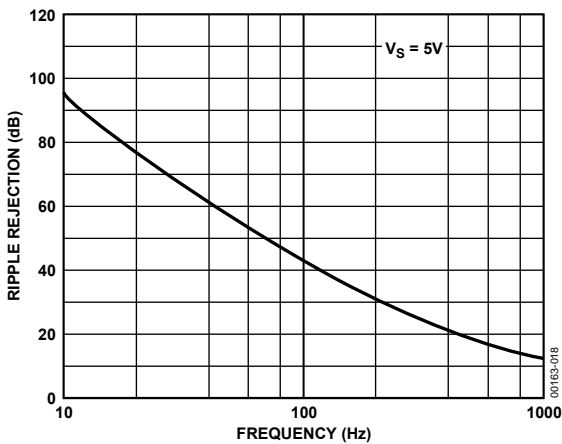


Figure 21. ADR291/ADR292 Ripple Rejection vs. Frequency



Figure 24. ADR292 Output Impedance vs. Frequency



Figure 25. ADR291 Load Transient



Figure 28. ADR291 Turn-On Time



Figure 26. ADR291 Load Transient



Figure 29. ADR291 Turn-Off Time



Figure 27. ADR291 Load Transient



Figure 30. Typical Hysteresis for the ADR291 Product

TERMINOLOGY

Line Regulation

Line regulation refers to the change in output voltage due to a specified change in input voltage. It includes the effects of self-heating. Line regulation is expressed as percent-per-volt, parts-per-million-per-volt, or microvolts-per-volt change in input voltage.

Load Regulation

The change in output voltage is due to a specified change in load current and includes the effects of self-heating. Load regulation is expressed in microvolts-per-milliampere, parts-per-million-per-milliampere, or ohms of dc output resistance.

Long-Term Stability

Long-term stability refers to the typical shift of output voltage at 25°C on a sample of parts subjected to a test of 1000 hours at 125°C.

$$\Delta V_{OUT} = V_{OUT}(t_0) - V_{OUT}(t_1)$$

$$\Delta V_{OUT} [\text{ppm}] = \frac{V_{OUT}(t_0) - V_{OUT}(t_1)}{V_{OUT}(t_0)} \times 10^6$$

where:

$V_{OUT}(t_0)$ = V_{OUT} at 25°C at Time 0.

$V_{OUT}(t_1)$ = V_{OUT} at 25°C after 1000 hours of operation at 125°C.

Temperature Coefficient

Temperature coefficient is the change of output voltage over the operating temperature change, normalized by the output voltage at 25°C, expressed in ppm/°C. The equation follows:

$$TCV_o [\text{ppm}/^\circ\text{C}] = \frac{V_o(T_2) - V_o(T_1)}{V_o(25^\circ\text{C}) \times (T_2 - T_1)} \times 10^6$$

where:

$V_{OUT}(25^\circ\text{C})$ = V_{OUT} at 25°C.

$V_{OUT}(T_1)$ = V_{OUT} at Temperature 1.

$V_{OUT}(T_2)$ = V_{OUT} at Temperature 2.

NC = no connect.

There are internal connections at NC pins that are reserved for manufacturing purposes. Users should not connect anything at the NC pins.

Thermal Hysteresis

Thermal hysteresis is defined as the change of output voltage after the device is cycled through temperatures from +25°C to -40°C, then to +85°C, and back to +25°C. This is a typical value from a sample of parts put through such a cycle.

$$V_{OUT-HYS} = V_{OUT}(25^\circ\text{C}) - V_{OUT_TC}$$

$$V_{OUT-HYS} [\text{ppm}] = \frac{V_{OUT}(25^\circ\text{C}) - V_{OUT_TC}}{V_{OUT}(25^\circ\text{C})} \times 10^6$$

where:

$V_{OUT}(25^\circ\text{C})$ = V_{OUT} at 25°C.

V_{OUT_TC} = V_{OUT} at 25°C after temperature cycle from +25°C to -40°C, then to +85°C, and back to +25°C.

THEORY OF OPERATION

The ADR291/ADR292 series of references uses a reference generation technique known as XFET (eXtra implanted junction FET). This technique yields a reference with low noise, low supply current, and very low thermal hysteresis.

The core of the XFET reference consists of two junction field effect transistors, one having an extra channel implant to raise its pinch-off voltage. By running the two JFETs at the same drain current, the difference in pinch-off voltage can be amplified and used to form a highly stable voltage reference. The intrinsic reference voltage is around 0.5 V with a negative temperature coefficient of about -120 ppm/K. This slope is essentially locked to the dielectric constant of silicon and can be closely compensated by adding a correction term generated in the same fashion as the proportional-to-temperature (PTAT) term used to compensate band gap references. Because most of the noise of a band gap reference comes from the compensation circuitry, the intrinsic temperature coefficient offers a significant advantage (being about 30 times lower), and therefore, requiring less correction resulting in much lower noise.

The simplified schematic in Figure 31 shows the basic topology of the ADR291/ADR292 series. The temperature correction term is provided by a current source with a value designed to be proportional to absolute temperature. The general equation is

$$V_{OUT} = \Delta V_P \left(\frac{R1 + R2 + R3}{R1} \right) + (I_{PTAT})(R3)$$

where:

ΔV_P is the difference in pinch-off voltage between the two FETs.
 I_{PTAT} is the positive temperature coefficient correction current.

The various versions of the ADR291/ADR292 family are created by on-chip adjustment of R1 and R3 to achieve 2.500 V or 4.096 V at the reference output.

The process used for the XFET reference also features vertical NPN and PNP transistors, the latter of which are used as output devices to provide a very low dropout voltage.



Figure 31. ADR291/ADR292 Simplified Schematic

DEVICE POWER DISSIPATION CONSIDERATIONS

The ADR291/ADR292 family of references is guaranteed to deliver load currents to 5 mA with an input voltage that ranges from 2.7 V to 15 V (minimum supply voltage depends on the output voltage chosen). When these devices are used in applications with large input voltages, care should be exercised to avoid exceeding the published specifications for maximum power dissipation or junction temperature that could result in premature device failure. Use the following formula to calculate maximum junction temperature or dissipation of a device:

$$P_D = \frac{T_J - T_A}{\theta_{JA}}$$

where

T_J and T_A are the junction and ambient temperatures, respectively.

P_D is the device power dissipation.

θ_{JA} is the device package thermal resistance.

BASIC VOLTAGE REFERENCE CONNECTIONS

References, in general, require a bypass capacitor connected from the V_{OUT} pin to the GND pin. The circuit in Figure 32 illustrates the basic configuration for the ADR291/ADR292 family of references. Note that the decoupling capacitors are not required for circuit stability.



Figure 32. Basic Voltage Reference Configuration

NOISE PERFORMANCE

The noise generated by the ADR291/ADR292 family of references is typically less than 12 µV p-p over the 0.1 Hz to 10 Hz band. The noise measurement is made with a band-pass filter made of a 2-pole high-pass filter with a corner frequency at 0.1 Hz and a 2-pole low-pass filter with a corner frequency at 10 Hz.

TURN-ON TIME

Upon application of power (cold start), the time required for the output voltage to reach its final value within a specified error band is defined as the turn-on settling time. Two components normally associated with this are the time it takes for the active circuits to settle and for the thermal gradients on the chip to stabilize. Figure 28 shows the turn-on settling time for the ADR291.

VOLTAGE REGULATOR FOR PORTABLE EQUIPMENT

The ADR291/ADR292 family of references is ideal for providing a stable, low cost, and low power reference voltage in portable equipment power supplies. Figure 36 shows how the ADR291 and ADR292 can be used in a voltage regulator that not only has low output noise (as compared to switch mode design) and low power, but also a very fast recovery after current surges. Some precautions should be taken in the selection of the output capacitors. Too high an ESR (effective series resistance) could endanger the stability of the circuit. A solid tantalum capacitor, 16 V or higher, and an aluminum electrolytic capacitor, 10 V or higher, are recommended for C1 and C2, respectively. Also, the path from the ground side of C1 and C2 to the ground side of R1 should be kept as short as possible.



Figure 36. Voltage Regulator for Portable Equipment

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MS-012-AA
 CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 37. 8-Lead Standard Small Outline Package [SOIC_N]
 Narrow Body
 (R-8)
 Dimensions shown in millimeters and (inches)



COMPLIANT TO JEDEC STANDARDS MO-153-AA

Figure 38. 8-Lead Thin Shrink Small Outline Package [TSSOP]
 (RU-8)
 Dimensions shown in millimeters



COMPLIANT TO JEDEC STANDARDS TO-226-AA
 CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 39. 3-Lead Plastic Header-Style Package [TO-92]
 (T-3)
 Dimensions shown in inches and (millimeters)

ORDERING GUIDE

| Model¹ | Output Voltage | Initial Accuracy (±%) | Temperature Coefficient Max (ppm/°C) | Package Description | Package Option | Ordering Quantity |
|--------------------------|-----------------------|------------------------------|---|----------------------------|-----------------------|--------------------------|
| ADR291ERZ | 2.50 | 0.08 | 8 | 8-Lead SOIC_N | R-8 | 98 |
| ADR291ERZ-REEL7 | 2.50 | 0.08 | 8 | 8-Lead SOIC_N | R-8 | 1,000 |
| ADR291FRZ | 2.50 | 0.12 | 15 | 8-Lead SOIC_N | R-8 | 98 |
| ADR291FRZ-REEL | 2.50 | 0.12 | 15 | 8-Lead SOIC_N | R-8 | 2,500 |
| ADR291FRZ-REEL7 | 2.50 | 0.12 | 15 | 8-Lead SOIC_N | R-8 | 1,000 |
| ADR291GRZ | 2.50 | 0.24 | 25 | 8-Lead SOIC_N | R-8 | 98 |
| ADR291GRZ-REEL | 2.50 | 0.24 | 25 | 8-Lead SOIC_N | R-8 | 2,500 |
| ADR291GRZ-REEL7 | 2.50 | 0.24 | 25 | 8-Lead SOIC_N | R-8 | 1,000 |
| ADR291GRUZ | 2.50 | 0.24 | 25 | 8-Lead TSSOP | RU-8 | 98 |
| ADR291GRUZ-REEL | 2.50 | 0.24 | 25 | 8-Lead TSSOP | RU-8 | 1,000 |
| ADR291GRUZ-REEL7 | 2.50 | 0.24 | 25 | 8-Lead TSSOP | RU-8 | 1,000 |
| ADR291GT9Z | 2.50 | 0.24 | 25 | 3-Lead TO-92 | T-3 | 98 |
| ADR292ERZ | 4.096 | 0.07 | 8 | 8-Lead SOIC_N | R-8 | 98 |
| ADR292ERZ-REEL | 4.096 | 0.07 | 8 | 8-Lead SOIC_N | R-8 | 2,500 |
| ADR292FRZ | 4.096 | 0.10 | 15 | 8-Lead SOIC_N | R-8 | 98 |
| ADR292FRZ-REEL | 4.096 | 0.10 | 15 | 8-Lead SOIC_N | R-8 | 2,500 |
| ADR292FRZ-REEL7 | 4.096 | 0.10 | 15 | 8-Lead SOIC_N | R-8 | 1,000 |
| ADR292GRZ | 4.096 | 0.15 | 25 | 8-Lead SOIC_N | R-8 | 98 |
| ADR292GRZ-REEL7 | 4.096 | 0.15 | 25 | 8-Lead SOIC_N | R-8 | 1,000 |
| ADR292GRUZ | 4.096 | 0.24 | 25 | 8-Lead TSSOP | RU-8 | 98 |
| ADR292GRUZ-REEL7 | 4.096 | 0.15 | 25 | 8-Lead TSSOP | RU-8 | 1,000 |

¹ Z = RoHS Compliant Part.

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